

JIEJIE MICROELECTRONICS CO., LTD.

JCT816CH

Average gate power dissipation ($T_j=150$)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	20	W

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JieJie Microelectronics Co., Ltd.

FIG.1: Maximum power dissipation versus RMS on-state current

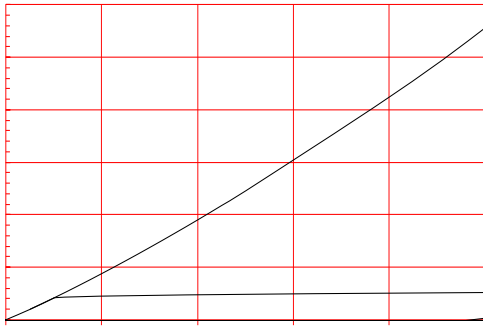
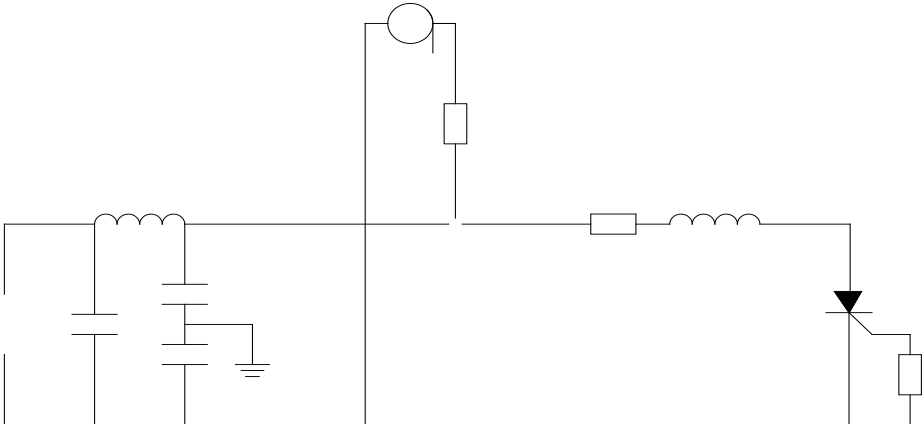


FIG.2: RMS on-state current versus case temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JCT816CH	800	15	TO-220C	50	Tube

Document Revision History

Date	Revision	Changes
Jun.15, 2023	A.	

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